

Parameter	Symbol	Values			Unit
		min.	typ.	max.	]
DC Characteristics					
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	20	-	-	V
$I_{\rm C} = 30 \text{ mA}, I_{\rm B} = 0$					
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	25	-	-	
<i>I</i> <sub>C</sub> = 10 μA, <i>I</i> <sub>E</sub> = 0					
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	5	-	-	
<i>I</i> <sub>E</sub> = 1 μA, <i>I</i> <sub>C</sub> = 0					
Collector-base cutoff current	I <sub>CBO</sub>				μA
$V_{\rm CB} = 25  \text{V},  I_{\rm E} = 0$		-	-	0.1	
$V_{\rm CB} = 25 \text{ V}, I_{\rm E} = 0$ , $T_{\rm A} = 150$		-	-	100	
DC current gain <sup>1)</sup>	h <sub>FE</sub>				-
I <sub>C</sub> = 5 mA, V <sub>CE</sub> = 10 V		50	-	-	
<i>I</i> <sub>C</sub> = 500 mA, <i>V</i> <sub>CE</sub> = 1 V, BCX69-10		85	100	160	
<i>I</i> <sub>C</sub> = 500 mA, <i>V</i> <sub>CE</sub> = 1 V, BCX69-16		100	160	250	
<i>I</i> <sub>C</sub> = 500 mA, <i>V</i> <sub>CE</sub> = 1 V, BCX69-25		160	250	375	
$I_{\rm C}$ = 1 A, $V_{\rm CE}$ = 1 V		60	-	-	
Collector-emitter saturation voltage <sup>1)</sup>	V <sub>CEsat</sub>	-	-	0.5	V
<i>I</i> <sub>C</sub> = 1 A, <i>I</i> <sub>B</sub> = 100 mA					
Base-emitter voltage <sup>1)</sup>	V <sub>BE(ON)</sub>				
I <sub>C</sub> = 5 mA, V <sub>CE</sub> = 10 V		-	0.6	-	
I <sub>C</sub> = 1 A, V <sub>CE</sub> = 1 V		-	-	1	
AC Characteristics	•				

#### **Electrical Characteristics** at $T_{\Delta} = 25^{\circ}$ C, unless otherwise specified

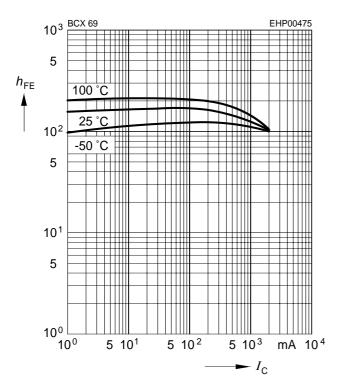
Transition frequency	f <sub>T</sub>	-	100	-	MHz
<i>I</i> <sub>C</sub> = 100 mA, <i>V</i> <sub>CE</sub> = 5 V, <i>f</i> = 20 MHz					

<sup>1</sup>Pulse test: t < 300 $\mu$ s; D < 2%

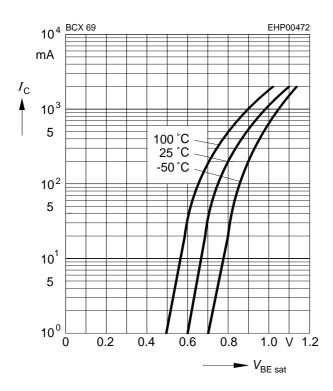


### **DC** current gain $h_{\text{FE}} = f(I_{\text{C}})$

 $V_{CE} = 1 V$ 

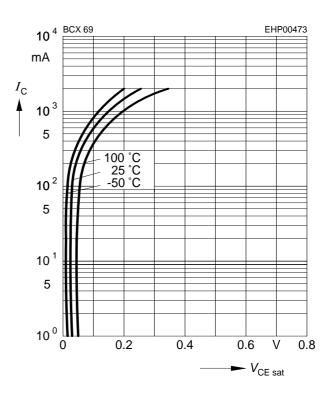


## **Base-emitter saturation voltage** $I_{\rm C} = f(V_{\rm BEsat}), h_{\rm FE} = 10$



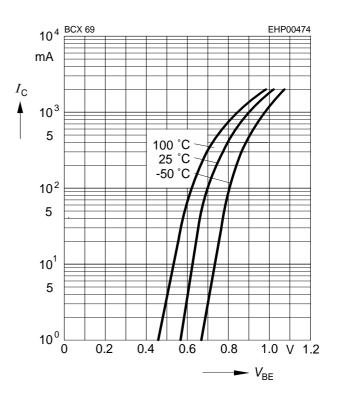
### **Collector-emitter saturation voltage**

 $I_{\rm C} = f(V_{\rm CEsat}), h_{\rm FE} = 10$ 



# Collector current $I_{\rm C}$ = $f(V_{\rm BE})$

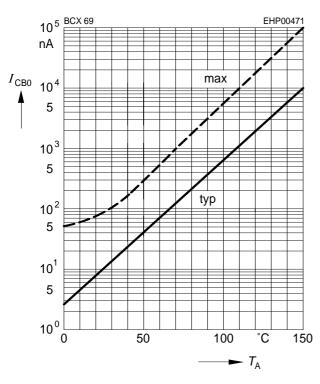
 $V_{CE} = 1V$ 



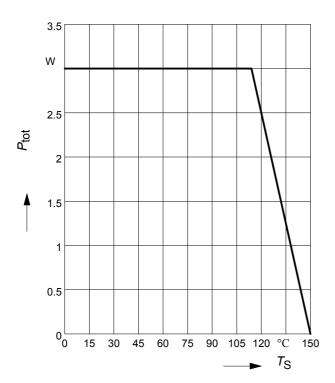


# **Collector cutoff current** $I_{CBO} = f(T_A)$

 $V_{CB}$  = 25 V

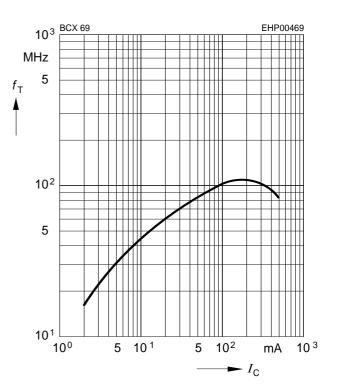


Total power dissipation  $P_{tot} = f(T_S)$ 

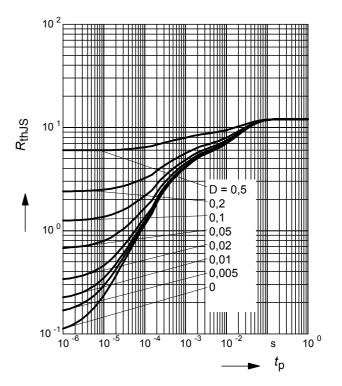


**Transition frequency**  $f_{\rm T} = f(I_{\rm C})$ 

 $V_{CE}$  = 5 V



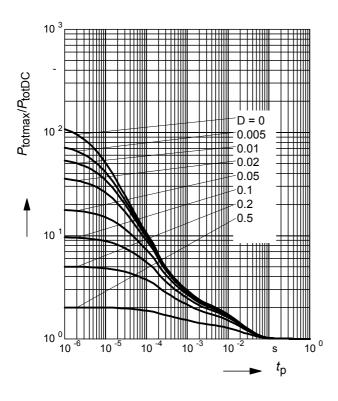
**Permissible Pulse Load**  $R_{\text{thJS}} = f(t_p)$ 



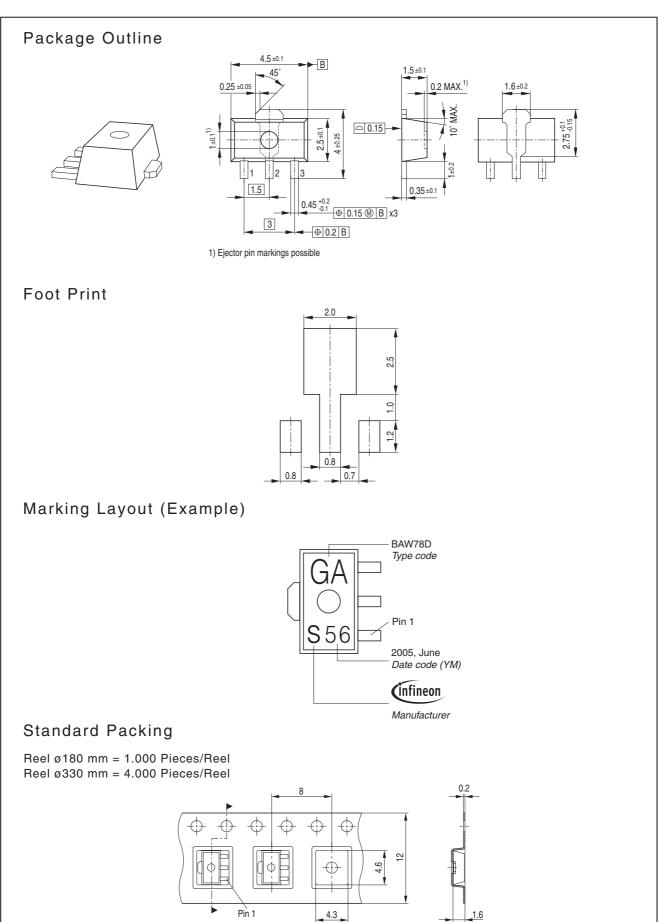


### Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$ 











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